NSN 5961-01-100-4177

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-100-4177 **Inclosure Material:** Ceramic and metal **Overall Length:** Between 0.160 inches and 0.180 inches **Terminal Length:** Between 0.325 inches and 0.375 inches **Overall Diameter:** Between 0.310 inches and 0.320 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Terminal and unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 80.0 breakdown voltage, collector-to-emitter, with base short-circuited to emitter and 75.0 collector to emitter voltage, dc **Current Rating Per Characteristic:** 100.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 30.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Test Data Document:** 13499-352-1065 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 flange and 2 pin Shelf Life: N/a **Unit Of Measure:**

Demilitarization:

No

Fiig:

A110a0